

2N5401HR

Hi-Rel PNP bipolar transistor 150 V - 0.5 A

Features

BV _{CEO}	150 V
I _C (max)	0.5 A
H _{FE} at 10 V - 150 mA	> 60
Operating temperature range	-65°C to +200°C

- Hi-Rel PNP bipolar transistor
- Linear gain characteristics
- ESCC qualified
- European preferred part list EPPL
- Radiation level: lot specific total dose contact marketing for specified level

Description

The 2N5401HR is a silicon planar epitaxial PNP transistor in TO-18 and LCC-3 packages. It is specifically designed for aerospace Hi-Rel applications and ESCC qualified according to the 5202-014 specification. In case of conflict between this datasheet and ESCC detailed www.DataSpecification, the latter prevails.

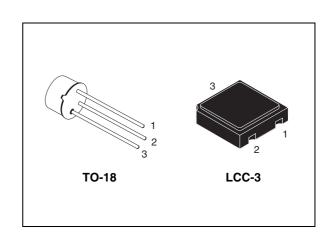


Figure 1. Internal schematic diagram

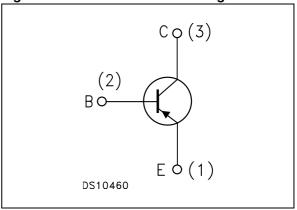


Table 1. Device summary

Order codes	Packages	Lead finish	Marking	Туре	EPPL	Packaging
2N5401HR	TO-18	Gold Solder Dip	520201401 520201402	ESCC Flight		Strip pack
2N5401T1	TO-18	Gold	2N5401T1	Engineering model		Strip pack
SOC5401	LCC-3	Gold	SOC5401	Engineering model		Waffle pack
SOC5401HRB	LCC-3	Gold Solder Dip	520201404 520201405	ESCC Flight	Yes	Waffle pack

January 2010 Doc ID 16934 Rev 1 1/8

Electrical ratings 2N5401HR

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-160	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-150	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-5	V
I _C	Collector current for 2N5401HR for SOC5401HRB	-0.6 -0.5	A A
P _{TOT}	Total dissipation at $T_{amb} \le 25~^{\circ}C$ for 2N5401HR for SOC5401HRB for SOC5401HRB $^{(1)}$ Total dissipation at $T_c \le 25~^{\circ}C$ for 2N5401HR	0.36 0.36 0.58	W W W
T _{STG}	Storage temperature	-65 to 200	°C
T _J	Max. operating junction temperature	200	°C

^{1.} When mounted on a 8x10x0.6 mm ceramic substrate.

Table 3. Thermal data for through-hole package

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max	146	°C/W
R_{thJA}	Thermal resistance junction-ambient max	486	°C/W

Table 4. Thermal data for SMD package

Symbol	Parameter	Value	Unit
R _{thJA}	Thermal resistance junction-ambient max Thermal resistance junction-ambient (1) max	486 302	°C/W

^{1.} When mounted on a 8x10x0.6 mm ceramic substrate.

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Parameter	Test co	Min.	Тур.	Max.	Unit	
I _{CBO}	Collector-base cut-off current (I _E = 0)	V _{CB} = -120 V V _{CB} = -120 V	T _C = 150 °C			-50 -50	nΑ μΑ
I _{EBO}	Emitter-base cut-off current (I _C = 0)	V _{EB} = -3 V				-50	nA
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA		-160			V
V _{(BR)CEO} (1)	Collector-emitter breakdown voltage (I _B = 0)	I _C = -1 mA		-150			V
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = -10 μA		-5			٧
V _{CE(sat)} (1)	Collector-emitter saturation voltage	$I_{C} = -10 \text{ mA}$ $I_{C} = -50 \text{ mA}$	$I_B = -1 \text{ mA}$ $I_B = -5 \text{ mA}$			-0.2 -0.5	> >
V _{BE(sat)} (1)	Base-emitter saturation voltage	•	$I_B = -1 \text{ mA}$ $I_B = -5 \text{ mA}$			-1 -1	V V
h _{FE} ⁽¹⁾	DC current gain	_	~-	50 60 60 20		240	
h _{fe}	Small signal current gain	V _{CE} = -10 V f = 10 kHz	$I_C = -10 \text{ mA}$	5			
C _{obo}	Output capacitance (I _E = 0)	V _{CB} = -10 V	f = 1 MHz			6	pF

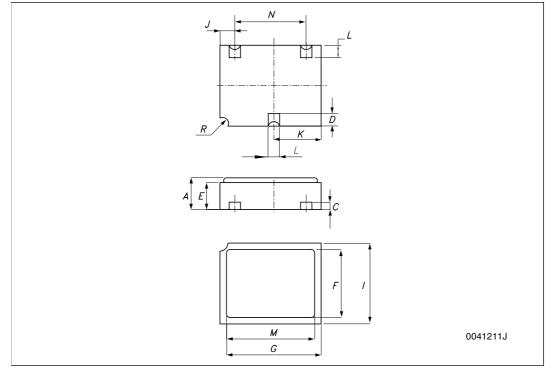
^{1.} Pulsed duration = 300 μ s, duty cycle \leq 2 %

3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

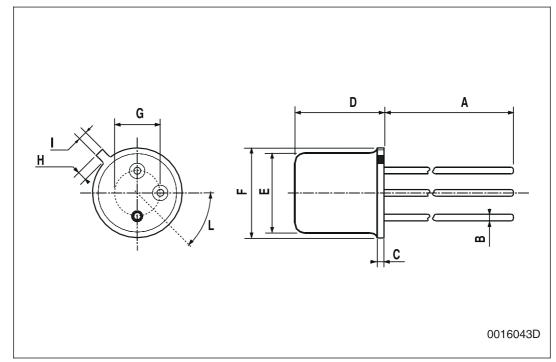
Ceramic Leadless Chip Carrier 3 mechanical data

DIM		mm.				
DIM.	MIN.	TYP	MAX.			
А	1.16		1.42			
С	0.45	0.50	0.56			
D		0.76				
E		1				
F	1.90		2.15			
G	2.90		3.25			
I	2.40		2.74			
J	0.40	0.57	0.80			
К	1.35	1.52	1.75			
L		0.50				
М	2.40		2.65			
N		1.90				
R		0.30				



TO-18 Mechanical data

DIM.	mm			inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А		12.7			0.500		
В			0.49			0.019	
D			5.3			0.208	
E			4.9			0.193	
F			5.8			0.228	
G	2.54			0.100			
Н			1.2			0.047	
I			1.16			0.045	
L	45°			45°			



2N5401HR Revision history

4 Revision history

Table 6. Document revision history

Date	Revision	Changes
04-Jan-2010	1	Initial release

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

www.DataSheet4U.com

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2010 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

